74LVC4245A

Octal dual supply translating transceiver; 3-state

Rev. 13 — 27 August 2021

Product data sheet

1. General description

The 74LVC4245A is an octal dual supply translating transceiver featuring 3-state bus compatible outputs in both send and receive directions. It is designed to interface between a 3 V and 5 V bus in a mixed 3 V and 5 V supply environment. The device features an output enable input (\overline{OE}) and a send/receive input (DIR) for direction control. A HIGH on \overline{OE} causes the outputs to assume a high-impedance OFF-state, effectively isolating the buses. In suspend mode, when either supply is zero, there is no current path between supplies. $V_{CCA} \ge V_{CCB}$, except in suspend mode. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

2. Features and benefits

- 5 V tolerant inputs/outputs, for interfacing with 5 V logic
- Wide supply voltage range:
 - 3 V bus (V_{CC(B)}): 1.5 V to 3.6 V
 - 5 V bus (V_{CC(A)}): 1.5 V to 5.5 V
- CMOS low-power consumption
- TTL interface capability at 3.3 V
- Overvoltage tolerant control inputs to 5.5 V
- High-impedance when V_{CC(A)} = 0 V
- Complies with JEDEC standard no. JESD8B/JESD36
- Latch-up performance meets requirements of JESD78 Class 1
- · ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

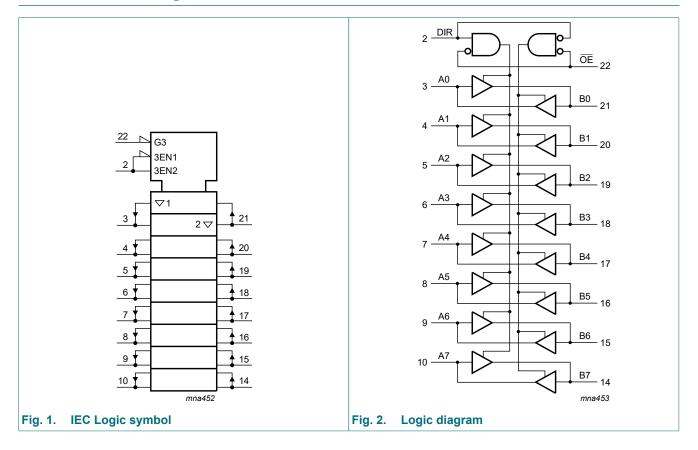
Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74LVC4245AD	-40 °C to +125 °C	SO24	plastic small outline package; 24 leads; body width 7.5 mm	SOT137-1					
74LVC4245APW	-40 °C to +125 °C	TSSOP24	plastic thin shrink small outline package; 24 leads; body width 4.4 mm	SOT355-1					
74LVC4245ABQ	-40 °C to +125 °C	DHVQFN24	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body 3.5 × 5.5 × 0.85 mm	SOT815-1					



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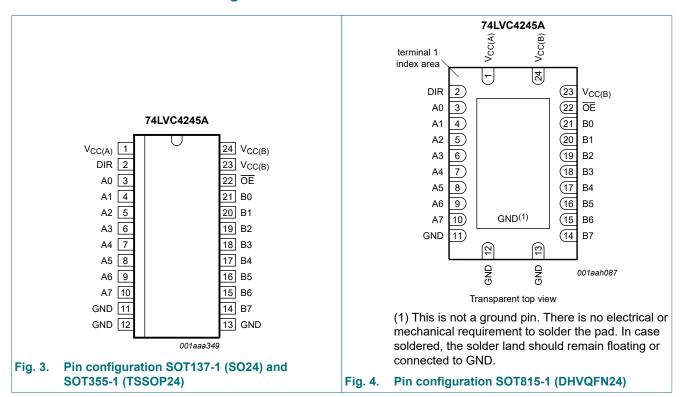
4. Functional diagram



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5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Table 2.1 III description									
Symbol	Pin	Description							
$V_{CC(A)}$	1	supply voltage (5 V bus)							
$V_{CC(B)}$	23, 24	supply voltage (3 V bus)							
GND	11, 12, 13	ground (0 V)							
DIR	2	direction control							
A0, A1, A2, A3, A4, A5, A6, A7	3, 4, 5, 6, 7, 8, 9, 10	data input or output							
B0, B1, B2, B3, B4, B5, B6, B7	21, 20, 19, 18, 17, 16, 15, 14	data input or output							
ŌE	22	output enable input (active LOW)							

6. Functional description

Table 3. Functional table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input		Input/output		
ŌĒ	DIR	An	Bn	
L	L	A = B	input	
L	Н	input	B = A	
Н	X	Z	Z	

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC(A)}	supply voltage A		-0.5	+6.5	V
V _{CC(B)}	supply voltage B		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+6.5	V
I _{OK}	output clamping current	$V_O > V_{CCO} \text{ or } V_O < 0 \text{ V}$ [2]	-	±50	mA
Vo	output voltage	output HIGH or LOW state [1]	-0.5	V _{CC} + 0.5	V
		output 3-state [1]	-0.5	+6.5	V
I _O	output current	$V_O = 0 \text{ V to } V_{CCO}$ [2]	-	±50	mA
I _{CC}	supply current		-	100	mA
I_{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [3]	-	500	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC(A)}	supply voltage A	V _{CC(A)} ≥ V _{CC(B)} ; see <u>Fig. 5</u> for maximum speed performance	1.5	-	5.5	V
V _{CC(B)}	supply voltage B	V _{CC(A)} ≥ V _{CC(B)} ; see <u>Fig. 5</u> for low-voltage applications	1.5	-	3.6	V
VI	input voltage	for control inputs	0	-	5.5	V
Vo	output voltage	output HIGH or LOW state	0	-	V _{CC}	V
		output 3-state	0	-	5.5	V
T _{amb}	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC(B)} = 2.7 V to 3.0 V	-	-	20	ns/V
		V _{CC(B)} = 3.0 V to 3.6 V	-	-	10	ns/V
		V _{CC(A)} = 3.0 V to 4.5 V	-	-	20	ns/V
		V _{CC(A)} = 4.5 V to 5.5 V	-	-	10	ns/V

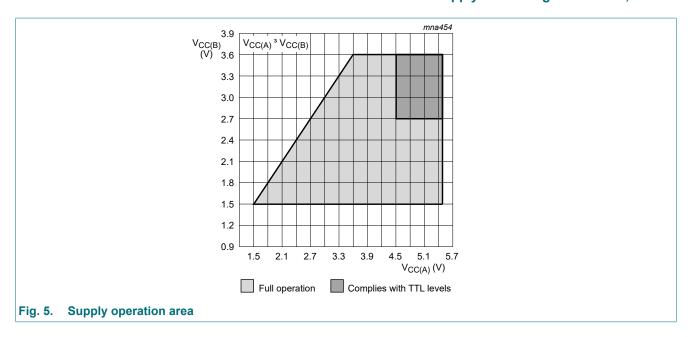
^[2] V_{CCO} is the supply voltage associated with the output.

^[3] For SOT137-1 (SO24) package: P_{tot} derates linearly with 16.2 mW/K above 119 °C.

For SOT355-1 (TSSOP24) package: P_{tot} derates linearly with 12.4 mW/K above 110 $^{\circ}\text{C}.$

For SOT815-1 (DHVQFN24) package: Ptot derates linearly with 15.0 mW/K above 117 °C.

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9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
T _{amb} = -	40 °C to +85 °C					
V _{IH}	HIGH-level input	V _{CC(B)} = 2.7 V to 3.6 V	2.0	-	-	V
	voltage	V _{CC(A)} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC(B)} = 2.7 V to 3.6 V	-	-	0.8	V
	voltage	V _{CC(A)} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	$V_{CC(B)}$ = 2.7 V to 3.6 V; I_{O} = -100 μ A	V _{CC(B)} - 0.2	V _{CC(B)}	-	V
		V _{CC(B)} = 2.7 V; I _O = -12 mA	V _{CC(B)} - 0.5	-	-	V
		$V_{CC(B)} = 3.0 \text{ V}; I_O = -24 \text{ mA}$		-	-	V
		$V_{CC(A)} = 4.5 \text{ V to } 5.5 \text{ V; } I_O = -100 \mu\text{A}$	V _{CC(A)} - 0.2	V _{CC(A)}	-	V
		$V_{CC(A)} = 4.5 \text{ V}; I_O = -12 \text{ mA}$		-	-	V
		V _{CC(A)} = 4.5 V; I _O = -24 mA	V _{CC(A)} - 0.8	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	$V_{CC(B)}$ = 2.7 V to 3.6 V; I _O = 100 μA		-	-	0.20	V
		V _{CC(B)} = 2.7 V; I _O = 12 mA	-	-	0.40	V
		V _{CC(B)} = 3.0 V; I _O = 24 mA	-	-	0.55	V
		V _{CC(A)} = 4.5 V to 5.5 V; I _O = 100 μA	-	-	0.20	V
		V _{CC(A)} = 4.5 V; I _O = 12 mA	-	-	0.40	V
		V _{CC(A)} = 4.5 V; I _O = 24 mA	-	-	0.55	V
l _l	input leakage current	V _I = 5.5 V or GND	-	±0.1	±5	μA
l _{OZ}	OFF-state output	$V_I = V_{IH} \text{ or } V_{IL}$ [2]				
	current	$V_{CC(B)} = 3.6 \text{ V}; V_O = V_{CC(B)} \text{ or GND}$	-	±0.1	±5	μΑ
		$V_{CC(A)} = 5.5 \text{ V}; V_O = V_{CC(A)} \text{ or GND}$	-	±0.1	±5	μΑ

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Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit	
I _{CC}	supply current	I _O = 0 A					
		$V_{CC(B)}$ = 3.6 V; other inputs at $V_{CC(B)}$ or GND	-	0.1	10	μΑ	
		$V_{CC(A)} = 5.5 \text{ V};$ other inputs at $V_{CC(A)}$ or GND	-	0.1	10	μA	
ΔI _{CC}	additional supply	per pin; I _O = 0 A					
	current	$V_{CC(B)}$ = 2.7 V to 3.6 V; V_I = $V_{CC(B)}$ - 0.6 V; other inputs at $V_{CC(B)}$ or GND	-	5	500	μA	
		$V_{CC(A)}$ = 4.5 V to 5.5 V; V_I = $V_{CC(A)}$ - 0.6 V; other inputs at $V_{CC(A)}$ or GND	-	5	500	μΑ	
Cı	input capacitance		-	4.0	-	pF	
C _{I/O}	input/output capacitance	An and Bn	-	5.0	-	pF	
T _{amb} = -4	40 °C to +125 °C						
V _{IH}	HIGH-level input	V _{CC(B)} = 2.7 V to 3.6 V	2.0	-	-	V	
	voltage	V _{CC(A)} = 4.5 V to 5.5 V	2.0	-	-	V	
V _{IL}	LOW-level input	V _{CC(B)} = 2.7 V to 3.6 V	-	-	0.8	V	
	voltage	V _{CC(A)} = 4.5 V to 5.5 V	-	-	0.8	V	
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	$V_{CC(B)}$ = 2.7 V to 3.6 V; I_{O} = -100 μ A	V _{CC(B)} - 0.3	-	-	V	
		V _{CC(B)} = 2.7 V; I _O = -12 mA	V _{CC(B)} - 0.65	-	-	V	
		V _{CC(B)} = 3.0 V; I _O = -24 mA	V _{CC(B)} - 1.0	-	-	V	
		$V_{CC(A)} = 4.5 \text{ V to } 5.5 \text{ V; } I_O = -100 \mu\text{A}$	V _{CC(A)} - 0.3	-	-	V	
		V _{CC(A)} = 4.5 V; I _O = -12 mA	V _{CC(A)} - 0.65	-	-	V	
		V _{CC(A)} = 4.5 V; I _O = -24 mA	V _{CC(A)} - 1.0	-	-	V	
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}					
	voltage	$V_{CC(B)}$ = 2.7 V to 3.6 V; I_{O} = 100 μ A	-	-	0.30	V	
		V _{CC(B)} = 2.7 V; I _O = 12 mA	-	-	0.60	V	
		V _{CC(B)} = 3.0 V; I _O = 24 mA	-	-	0.80	V	
		$V_{CC(A)} = 4.5 \text{ V to } 5.5 \text{ V; } I_O = 100 \mu\text{A}$	-	-	0.30	V	
		V _{CC(A)} = 4.5 V; I _O = 12 mA	-	-	0.60	V	
		V _{CC(A)} = 4.5 V; I _O = 24 mA	-	-	0.80	V	
I _I	input leakage current	V _I = 5.5 V or GND	-	-	±20	μΑ	
l _{OZ}	OFF-state output	$V_I = V_{IH} \text{ or } V_{IL}$ [2]					
	current $V_{CC(B)} = 3.6 \text{ V}; V_O = V_{CC(B)} \text{ or GND}$		-	-	±20	μΑ	
		$V_{CC(A)} = 5.5 \text{ V}; V_O = V_{CC(A)} \text{ or GND}$	-	-	±20	μΑ	
I _{CC}	supply current	I _O = 0 A					
		$V_{CC(B)}$ = 3.6 V; other inputs at $V_{CC(B)}$ or GND	-	-	40	μA	
		V _{CC(A)} = 5.5 V; other inputs at V _{CC(A)} or GND	-	-	40	μΑ	

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Symbol	Parameter	Conditions	Min	Typ [1]	Max	Unit
ΔI_{CC}	additional supply	per pin; I _O = 0 A				
	current	$V_{CC(B)}$ = 2.7 V to 3.6 V; V_I = $V_{CC(B)}$ - 0.6 V; other inputs at $V_{CC(B)}$ or GND	-	-	5000	μΑ
		$V_{CC(A)}$ = 4.5 V to 5.5 V; V_I = $V_{CC(A)}$ - 0.6 V; other inputs at $V_{CC(A)}$ or GND	-	-	5000	μΑ

^[1] All typical values are measured at $V_{CC(A)}$ = 5.0 V, $V_{CC(B)}$ = 3.3 V and T_{amb} = 25 °C.

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). $V_{CC(A)} = 4.5 \text{ V}$ to 5.5 V; $t_r = t_f \le 2.5 \text{ ns}$. For test circuit see Fig. 8.

Symbol	Parameter	Conditions	V _{CC(B)}	-40	°C to +8	5°C	-40 °C to	+125 °C	Unit
				Min	Typ [1]	Max	Min	Max	
t _{PHL}	HIGH to LOW	An to Bn; see Fig. 6	2.7 V	1.0	3.6	6.3	1.0	8.0	ns
	propagation delay		3.0 V to 3.6 V	1.0	3.3	6.3	1.0	8.0	ns
	delay	Bn to An; see Fig. 6	2.7 V	1.0	3.4	6.1	1.0	8.0	ns
			3.0 V to 3.6 V	1.0	3.4	6.1	1.0	8.0	ns
t _{PLH}	LOW to HIGH	An to Bn; see Fig. 6	2.7 V	1.0	3.3	6.7	1.0	8.5	ns
	propagation delay		3.0 V to 3.6 V	1.0	2.8	6.5	1.0	8.5	ns
	delay	Bn to An; see Fig. 6	2.7 V	1.0	3.0	5.0	1.0	6.5	ns
			3.0 V to 3.6 V	1.0	3.0	5.0	1.0	6.5	ns
t _{PZL}	OFF-state	OE to An; see Fig. 7	2.7 V	1.0	4.5	9.0	1.0	11.5	ns
	to LOW		3.0 V to 3.6 V	1.0	4.5	9.0	1.0	11.5	ns
	propagation delay	OE to Bn; see Fig. 7	2.7 V	1.0	4.4	8.7	1.0	11.0	ns
			3.0 V to 3.6 V	1.0	3.8	8.1	1.0	10.5	ns
t _{PZH}	OFF-state	HIGH ,	2.7 V	1.0	4.5	8.1	1.0	10.5	ns
	to HIGH propagation		3.0 V to 3.6 V	1.0	4.5	8.1	1.0	10.5	ns
	delay	OE to Bn; see Fig. 7	2.7 V	1.0	4.3	8.7	1.0	11.0	ns
	,		3.0 V to 3.6 V	1.0	3.2	8.1	1.0	10.5	ns
t _{PLZ}	LOW to	OE to An; see Fig. 7	2.7 V	1.0	2.9	7.0	1.0	9.0	ns
	OFF-state propagation		3.0 V to 3.6 V	1.0	2.9	7.0	1.0	9.0	ns
	delay	OE to Bn; see Fig. 7	2.7 V	1.0	3.9	7.7	1.0	10.0	ns
			3.0 V to 3.6 V	1.0	3.5	7.7	1.0	10.0	ns
t _{PHZ}	HIGH to	OE to An; see Fig. 7	2.7 V	1.0	2.8	5.8	1.0	7.5	ns
	OFF-state		3.0 V to 3.6 V	1.0	2.8	5.8	1.0	7.5	ns
	propagation delay	OE to Bn; see Fig. 7	2.7 V	1.0	3.3	7.8	1.0	10.0	ns
	_		3.0 V to 3.6 V	1.0	2.9	7.8	1.0	10.0	ns
t _{sk(o)}	output skew time		[2]	-	-	1.0	-	1.5	ns

^[2] For transceivers, the parameter I_{OZ} includes the input leakage current.

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Symbol	Parameter	Conditions	V _{CC(B)}	-40	-40 °C to +85 °C		-40 °C to	+125 °C	Unit
				Min	Typ [1]	Max	Min	Max	
C _{PD}	power dissipation capacitance	5 V bus: Bn to An; $V_I = GND$ to $V_{CC(A)}$; $V_{CC(A)} = 5.0 \text{ V}$	[3]						
		outputs enabled	-	-	17	-	-	-	pF
		outputs disabled	-	-	5	-	-	-	pF
		3 V bus: An to Bn; V_I = GND to $V_{CC(B)}$; $V_{CC(B)}$ = 3.3 V	[3]						
		outputs enabled	-	-	17	-	-	-	pF
		outputs disabled	-	-	5	-	-	-	pF

- Typical values are measured at T_{amb} = 25 °C, $V_{CC(A)}$ = 5.0 V, and $V_{CC(B)}$ = 2.7 V and 3.3 V respectively. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.
- C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz; f_o = output frequency in MHz

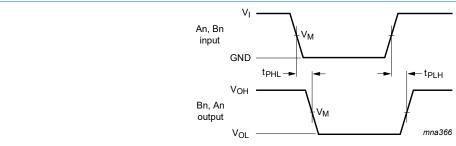
C_L = output load capacitance in pF

V_{CC} = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs

10.1. Waveforms and test circuit

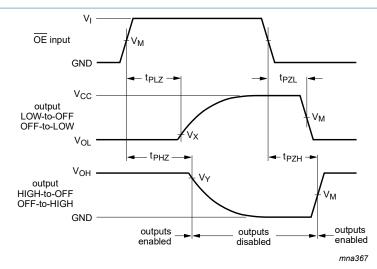


Measurement point are given in Table 8.

V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Input (An, Bn) to output (Bn, An) propagation delays

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Measurement point are given in Table 8.

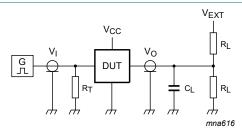
 V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig. 7. 3-state enable and disable times

Table 8. Measurement points

Supply volt	age	Input	Input		Output			
V _{CC(A)}	V _{CC(B)}	V _M [1]	V _I [1]	V _M [2]	V _X	V _Y		
≤ 2.7 V	≤ 2.7 V	0.5 V _{CCI}	V _{CCI}	0.5 V _{CCO}	-	-		
-	2.7 V to 3.6 V	1.5 V	2.7 V	1.5 V	-	-		
≥ 4.5 V	-	0.5 V _{CCI}	3.0 V	0.5 V _{CCO}	-	-		
-	≥ 2.7 V	-	V _{CCI}	-	V _{OL} + 0.3 V	V _{OH} - 0.3 V		

- [1] V_{CCI} is the supply voltage associated with the data input port.
- [2] V_{CCO} is the supply voltage associated with the data output port.



Test data is given in Table 9. Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig. 8. Test circuit for measuring switching times

Table 9. Test data

Supply voltage		Input	Load		V _{EXT}	V _{EXT}			
V _{CC(A)}	V _{CC(B)}	V _I [1]	CL	R _L	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ} [2]		
< 2.7 V	< 2.7 V	V _{CCI}	50 pF	500 Ω	open	GND	2 × V _{CCO}		
-	2.7 V to 3.6 V	2.7 V	50 pF	500 Ω	open	GND	2 × V _{CCO}		
4.5 V to 5.5 V	-	3.0 V	50 pF	500 Ω	open	GND	2 × V _{CCO}		

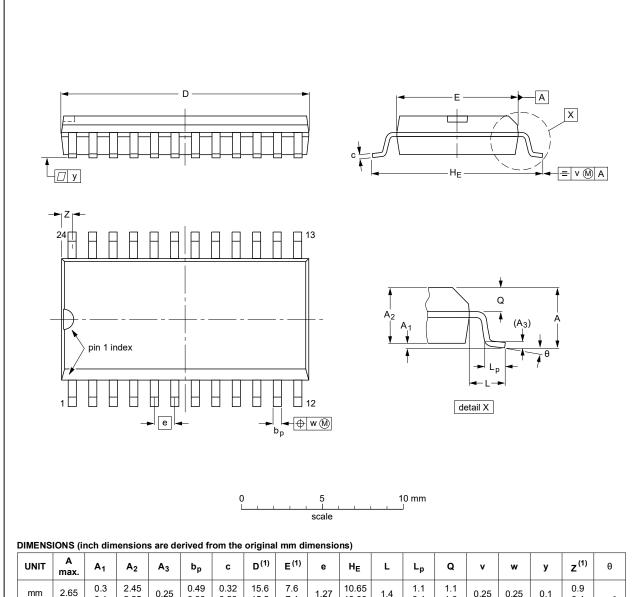
- [1] V_{CCI} is the supply voltage associated with the data input port.
- [2] V_{CCO} is the supply voltage associated with the output port.

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11. Package outline

SO24: plastic small outline package; 24 leads; body width 7.5 mm

SOT137-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	15.6 15.2	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.61 0.60	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

	OUTLINE		REFER	EUROPEAN	ISSUE DATE		
	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	SOT137-1	075E05	MS-013				99-12-27 03-02-19

Fig. 9. Package outline SOT137-1 (SO24)

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TSSOP24: plastic thin shrink small outline package; 24 leads; body width 4.4 mm

SOT355-1

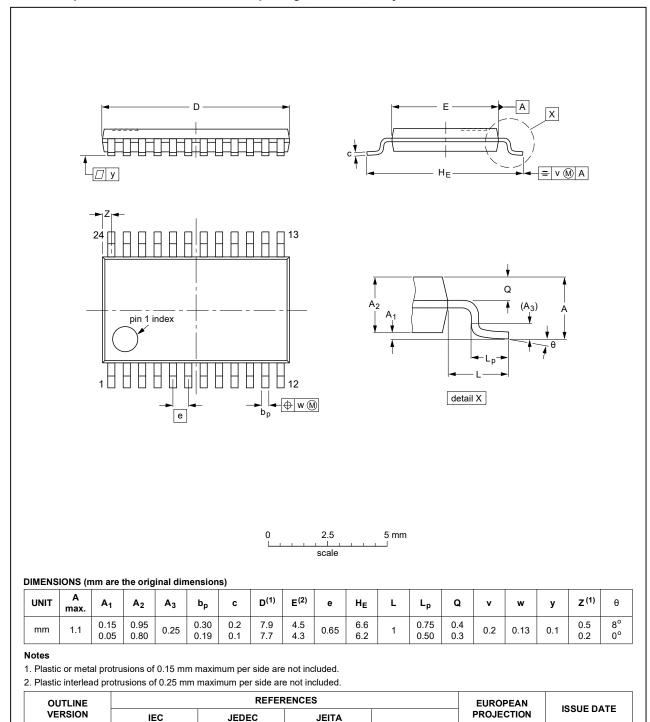


Fig. 10. Package outline SOT355-1 (TSSOP24)

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SOT355-1

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DHVQFN24: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 24 terminals; body $3.5 \times 5.5 \times 0.85$ mm

SOT815-1

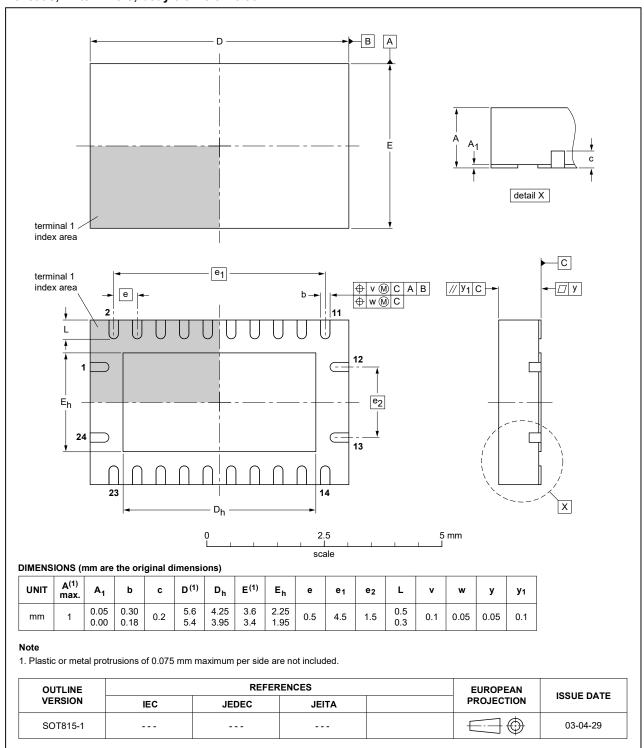


Fig. 11. Package outline SOT815-1 (DHVQFN24)

Octal dual supply translating transceiver; 3-state

12. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes					
74LVC4245A v.13	20210827	Product data sheet	-	74LVC4245A v.12					
Modifications:	Type numb	Type number 74LVC4245ADB (SOT340-1/SSOP24) removed.							
74LVC4245A v.12	20210412	20210412 Product data sheet -		74LVC4245A v.11					
Modifications:	Section 9: A	Section 9: ΔI _{CC} conditions have changed.							
74LVC4245A v.11	20200922	Product data sheet	-	74LVC4245A v.10					
Modifications:	guidelines of Legal texts Section 1 u Table 4: De	• Section 1 updated.							
74LVC4245A v.10	20121218	Product data sheet	-	74LVC4245A v.9					
Modifications:	V _{CC(A}) and	 V_{CC(A)} and V_{CC(B)} changed into V_{CC(A)} and V_{CC(B)} (errata) 							
74LVC4245A v.9	20121120	Product data sheet	-	74LVC4245A v.8					
Modifications:	• <u>Fig. 4</u> : Pin	configuration drawing corre	ected for DHVQFN	24 package					
74LVC4245A v.8	20111122	Product data sheet	-	74LVC4245A v.7					
74LVC4245A v.7	20110812	Product data sheet	-	74LVC4245A v.6					
74LVC4245A v.6	20080118	Product data sheet	-	74LVC4245A v.5					
74LVC4245A v.5	20040330	Product specification	-	74LVC4245A v.4					
74LVC4245A v.4	20040211	Product specification	-	74LVC4245A v.3					
74LVC4245A v.3	19990615	Product specification	-	74LVC4245A v.2					
74LVC4245A v.2	19980729	Product specification	-	74LVC4245A v.1					
74LVC4245A v.1	19980729	Product specification	-	-					

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition	
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.	
Product [short] data sheet	Production	This document contains the product specification.	

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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